BIRLA INSTITUTE OF TECHNOLOGY, MESRA, RANCHI (MID SEMESTER EXAMINATION)

CLASS: BTECH SEMESTER: I
BRANCH: CS/IT/ECE/EEE SESSION: MO/2018

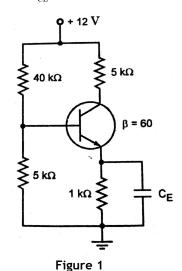
SUBJECT: EC101 BASICS OF ELECTRONICS & COMM. ENGG.

TIME: 2 HOURS FULL MARKS: 25

INSTRUCTIONS:

- 1. The total marks of the questions are 25.
- 2. Candidates may attempt for all 25 marks.
- 3. Before attempting the question paper, be sure that you have got the correct question paper.
- 4. The missing data, if any, may be assumed suitably.

- Q1. (a) What is an ideal diode? Draw its equivalent circuit and V-I characteristics. [2]
- Q1. (b) Explain the static and dynamic resistance of the p-n junction diode using the V-I [3] characteristics. Determine the ac resistance for a semiconductor diode (Silicon) having a forward bias voltage of 200 mV and reverse saturation current of 1 μ A at room temperature (300 $^{\circ}$ K).
- Q2. (a) A half-wave rectifier uses a diode with a forward resistance of 100Ω . If the input ac voltage is 220 V (rms) and the load resistance is of $2k\Omega$, determine (i) the peak inverse voltage when the diode is ideal, (ii) the transformer utilization factor.
- Q2. (b) Derive the expression for ripple factor in a full wave rectifier circuit (center-tap type) [3] with shunt capacitor filter.
- Q3. (a) Draw the input and output characteristics of Common-base transistor configuration. [2] Derive the relation between α and β .
- Q3. (b) Calculate the values of I_c , I_B and V_{CE} for the circuit of figure 1. [3]



- Q4. (a) List out the advantages of the FET over conventional BJT? Determine the relation [2] between the drain resistance, transconductance and amplification factor of FET.
- Q4. (b) With the help of neat sketches explain the construction and operation of p-channel [3] enhancement type MOSFET.
- Q5. (a) A transistor amplifier with negative feedback has a voltage gain of 600 without feedback, and 50 with feedback. Calculate the percentage of output which is feedback to the input.
- Q5. (b) Draw and explain the Hartley oscillator circuit using an n-p-n transistor. Write the [3] expression for frequency of oscillation for it.

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